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# MOS INTEGRATED CIRCUIT $\mu PD448012-X$

## 8M-BIT CMOS STATIC RAM 512K-WORD BY 16-BIT EXTENDED TEMPERATURE OPERATION

#### **Description**

The  $\mu$ PD448012-X is a high speed, low power, 8,388,608 bits (524,288 words by 16 bits) CMOS static RAM.

The  $\mu$ PD448012-X has two chip enable pins (/CE1, CE2) to extend the capacity.

The μPD448012-X is packed in 48-pin PLASTIC TSOP (I) (Normal bent).

#### **Features**

• 524,288 words by 16 bits organization

• Fast access time: 55, 70, 85, 100, 120 ns (MAX.)

• Byte data control: /LB (I/O1 - I/O8), /UB (I/O9 - I/O16)

• Low voltage operation

(B version: Vcc = 2.7 to 3.6 V, C version: Vcc = 2.2 to 3.6 V)

• Low Vcc data retention: 1.0 V (MIN.)

Operating ambient temperature: T<sub>A</sub> = −25 to +85°C

• Output Enable input for easy application

• Two Chip Enable inputs: /CE1, CE2

Part number	Access time	Operating supply	Operating ambient		Supply current	
	ns (MAX.)	voltage	temperature	mperature At operating		At data retention
		V	°C	mA (MAX.)	μA (MAX.)	μA (MAX.)
μPD448012-BxxX	55, 70, 85, 100	2.7 to 3.6	–25 to +85	45 Note	15	6
μPD448012-CxxX	70, 85, 100, 120	2.2 to 3.6		45		

**Note** Cycle time  $\geq$  70 ns,  $\mu$ PD448012-B55X : 50 mA

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## **Ordering Information**

Part number	Package	Access time	Operating	Operating	Remark
		ns (MAX.)	supply voltage	temperature	
			V	°C	
μPD448012GY-B55X-MJH	48-pin PLASTIC TSOP (I)	55	2.7 to 3.6	–25 to +85	B version
μPD448012GY-B70X-MJH	(12x18) (Normal bent)	70			
μPD448012GY-B85X-MJH		85			
μPD448012GY-B10X-MJH		100			
μPD448012GY-C70X-MJH		70	2.2 to 3.6		C version
μPD448012GY-C85X-MJH		85			
μPD448012GY-C10X-MJH		100			
μPD448012GY-C12X-MJH		120			
μPD448012GY-B55X-MJH-A		55	2.7 to 3.6		B version
μPD448012GY-B70X-MJH-A		70			
μPD448012GY-B85X-MJH-A		85			
μPD448012GY-B10X-MJH-A		100			
μPD448012GY-C70X-MJH-A		70	2.2 to 3.6		C version
μPD448012GY-C85X-MJH-A		85	]		
μPD448012GY-C10X-MJH-A		100			
μPD448012GY-C12X-MJH-A		120	]		

**Remark** Products with -A at the end of the part number are lead-free products.

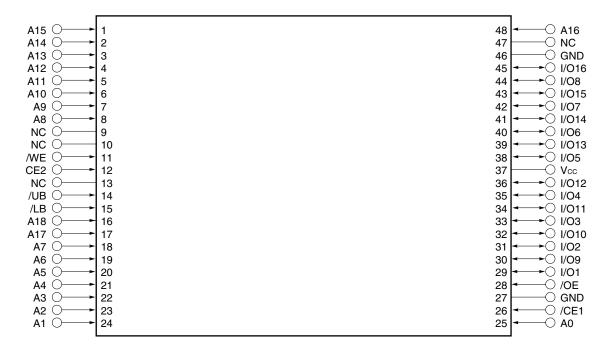


#### Pin Configuration (Marking Side)

/xxx indicates active low signal.

#### 48-pin PLASTIC TSOP (I) (12x18) (Normal bent)

[ μPD448012GY-BxxX-MJH ]
[ μPD448012GY-CxxX-MJH ]
[ μPD448012GY-BxxX-MJH-A ]
[ μPD448012GY-CxxX-MJH-A ]



A0 - A18 : Address inputs

I/O1 - I/O16 : Data inputs / outputs

/CE1, CE2 : Chip Enable 1, 2

/WE : Write Enable
/OE : Output Enable

/LB, /UB : Byte data select

Vcc : Power supply

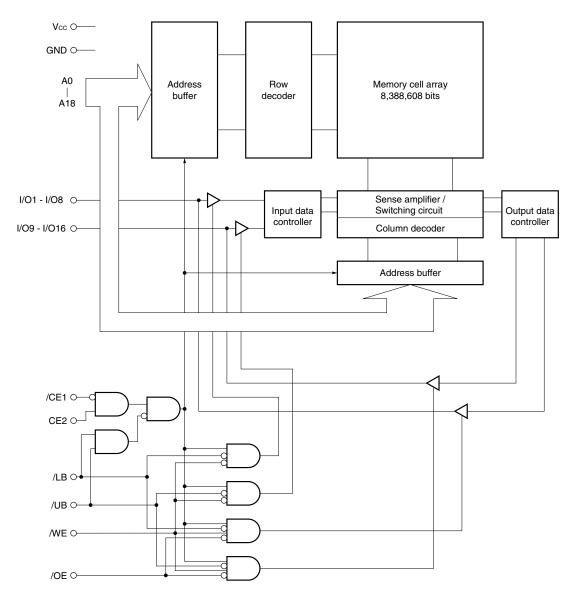
GND : Ground

NC : No Connection

**Remark** Refer to **Package Drawing** for the 1-pin index mark.

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## **Block Diagram**



**Truth Table** 

/CE1	CE2	/OE	/WE	/LB	/UB	Mode	1/	0	Supply current
							I/O1 - I/O8	I/O9 - I/O16	
Н	×	×	×	×	×	Not selected	High impedance	High impedance	Isв
×	L	×	×	×	×				
L	Н	Н	Н	×	×	Output disable	High impedance	High impedance	ICCA
		L	Н	L	L	Word read	<b>D</b> оит	<b>D</b> оит	
				L	Н	Lower byte read	<b>D</b> оит	High impedance	
				Н	L	Upper byte read	High impedance	<b>D</b> оит	
		×	L	L	L	Word write	Din	Din	
				L	Н	Lower byte write	Din	High impedance	
				Н	L	Upper byte write	High impedance	Din	
×	×	×	×	Н	Н	Not selected	High impedance	High impedance	lsв

Remark ×: VIH or VIL



#### **Electrical Specifications**

#### **Absolute Maximum Ratings**

Parameter	Symbol	Condition	Rating	Unit
Supply voltage	Vcc		-0.5 Note to +4.0	V
Input / Output voltage	VT		-0.5 Note to Vcc + 0.4 (4.0 V MAX.)	V
Operating ambient temperature	TA		-25 to +85	°C
Storage temperature	Tstg		-55 to +125	°C

Note -3.0 V (MIN.) (Pulse width: 30 ns)

Caution Exposing the device to stress above those listed in Absolute Maximum Rating could cause permanent damage. The device is not meant to be operated under conditions outside the limits described in the operational section of this specification. Exposure to Absolute Maximum Rating conditions for extended periods may affect device reliability.

#### **Recommended Operating Conditions**

Parameter	Symbol	Condition	μPD4480	)12-BxxX	μPD4480	Unit	
			MIN.	MAX.	MIN.	MAX.	
Supply voltage	Vcc		2.7	3.6	2.2	3.6	V
High level input voltage	VIH	2.7 V ≤ Vcc ≤ 3.6 V	2.4	Vcc + 0.4	2.4	Vcc + 0.4	٧
		2.2 V ≤ Vcc < 2.7 V	_	_	2.0	Vcc + 0.3	
Low level input voltage	VIL		-0.3 Note	+0.5	-0.3 Note	+0.3	٧
Operating ambient temperature	TA		-25	+85	-25	+85	°C

Note -1.5 V (MIN.) (Pulse width: 30 ns)

#### Capacitance (T<sub>A</sub> = 25°C, f = 1 MHz)

Parameter	Symbol	Test condition	MIN.	TYP.	MAX.	Unit
Input capacitance	Cin	V <sub>IN</sub> = 0 V			8	pF
Input / Output capacitance	Ci/o	V <sub>1/0</sub> = 0 V			10	pF

Remarks 1. VIN: Input voltage, VI/O: Input / Output voltage

2. These parameters are not 100% tested.

Data Sheet M14466EJ7V0DS 5



#### DC Characteristics (Recommended Operating Conditions Unless Otherwise Noted) (1/2)

Parameter	Symbol	Test cor	ndition		Vcc ≥ 2.	7 V	Unit
					μPD448012	2-BxxX	
				MIN.	TYP.	MAX.	
Input leakage current	lu	V <sub>IN</sub> = 0 V to V <sub>CC</sub>		-1.0		+1.0	μΑ
I/O leakage current	ILO	V <sub>I/O</sub> = 0 V to V <sub>CC</sub> , /CE1 =	· VIH Or	-1.0		+1.0	μΑ
		CE2 = VIL or /WE = VIL o	or /OE = V <sub>IH</sub>				
Operating supply current	Icca1	/CE1 = V <sub>IL</sub> , CE2 = V <sub>IH</sub> ,	Cycle time = 55 ns		_	50	mA
		Minimum cycle time,	Cycle time ≥ 70 ns		-	45	
		I <sub>I/O</sub> = 0 mA					
	Icca2	/CE1 = VIL, CE2 = VIH, II	o = 0 mA,		-	4	
		Cycle time = ∞					
	Іссаз	/CE1 ≤ 0.2 V, CE2 ≥ Vcc	e – 0.2 V,		1	6	
		Cycle time = 1 $\mu$ s, I <sub>I/O</sub> =	0 mA,				
		$V_{IL} \le 0.2 \text{ V}, \text{ V}_{IH} \ge V_{CC} - 0.00$	).2 V				
Standby supply current	IsB	/CE1 = V <sub>IH</sub> or CE2 = V <sub>IL</sub>	or /LB = /UB = V <sub>IH</sub>		-	0.6	mA
	I <sub>SB1</sub>	/CE1 ≥ Vcc - 0.2 V, CE2	2 ≥ Vcc – 0.2 V		1.0	15	μА
	I <sub>SB2</sub>	CE2 ≤ 0.2 V			1.0	15	
	I <sub>SB3</sub>	/LB = /UB ≥ Vcc - 0.2 V,			1.0	15	
		/CE1 ≤ 0.2 V, CE2 ≥ Vcc	c – 0.2 V				
High level output voltage	Vон	Iон = -0.5 mA		2.4			V
Low level output voltage	Vol	IoL = 1.0 mA				0.4	V

Remarks 1. VIN: Input voltage, VI/O: Input / Output voltage

2. These DC characteristics are in common regardless of product classification.



## DC Characteristics (Recommended Operating Conditions Unless Otherwise Noted) (2/2)

Parameter	Symbol	Test condition			Vcc ≥ 2.2 V		Unit
				μF	PD448012-Cx	хX	
				MIN.	TYP.	MAX.	
Input leakage current	lu	V <sub>IN</sub> = 0 V to V <sub>CC</sub>		-1.0		+1.0	μА
I/O leakage current	ILO	V <sub>I/O</sub> = 0 V to V <sub>CC</sub> , /CE1 = V <sub>IH</sub> or	r	-1.0		+1.0	μА
		CE2 = V <sub>IL</sub> or /WE = V <sub>IL</sub> or /OE	= V <sub>IH</sub>				
Operating supply current	Icca1	/CE1 = V <sub>IL</sub> , CE2 = V <sub>IH</sub> , Minimu	m cycle time,		_	45	mA
		Ivo = 0 mA		_	30		
	Icca2	/CE1 = V <sub>IL</sub> , CE2 = V <sub>IH</sub> , I <sub>I/O</sub> = 0 I	mA,		-	4	
		Cycle time = ∞	Cycle time = ∞ Vcc ≤ 2.7 V		-	2	
	Іссаз	/CE1 ≤ 0.2 V, CE2 ≥ Vcc – 0.2	V,		-	6	
		Cycle time = 1 $\mu$ s, I <sub>I/O</sub> = 0 mA,	$V_{IL} \leq 0.2 V$ ,				
		V <sub>IH</sub> ≥ V <sub>CC</sub> − 0.2 V	Vcc ≤ 2.7 V		-	5	
Standby supply current	Isa	/CE1 = V <sub>IH</sub> or CE2 = V <sub>IL</sub> or			-	0.6	mA
		/LB = /UB = V <sub>IH</sub>	Vcc ≤ 2.7 V		-	0.6	
	I <sub>SB1</sub>	/CE1 ≥ Vcc - 0.2 V,			1.0	15	μА
		CE2 ≥ Vcc - 0.2 V	Vcc ≤ 2.7 V		0.9	13	
	I <sub>SB2</sub>	CE2 ≤ 0.2 V			1.0	15	
			Vcc ≤ 2.7 V		0.9	13	
	I <sub>SB3</sub>	/LB = /UB ≥ Vcc - 0.2 V, /CE1	/LB = /UB ≥ Vcc – 0.2 V, /CE1 ≤ 0.2 V,		1.0	15	
		CE2 ≥ Vcc - 0.2 V	Vcc ≤ 2.7 V		0.9	13	
High level output voltage	Vон	Iон = -0.5 mA	•	2.4			٧
			Vcc ≤ 2.7 V	1.8			
Low level output voltage	Vol	IoL = 1.0 mA				0.4	٧

Remarks 1. VIN: Input voltage, VI/O: Input / Output voltage

2. These DC characteristics are in common regardless of product classification.

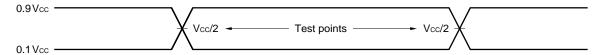


#### AC Characteristics (Recommended Operating Conditions Unless Otherwise Noted)

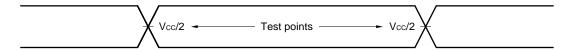
#### **AC Test Conditions**

#### [ $\mu$ PD448012-B55X, $\mu$ PD448012-B70X, $\mu$ PD448012-B85X, $\mu$ PD448012-B10X ]

Input Waveform (Rise and Fall Time ≤ 5 ns)



**Output Waveform** 

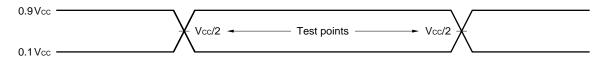


#### **Output Load**

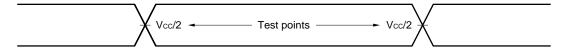
1TTL + 50 pF

#### [ $\mu$ PD448012-C70X, $\mu$ PD448012-C85X, $\mu$ PD448012-C10X, $\mu$ PD448012-C12X ]

Input Waveform (Rise and Fall Time ≤ 5 ns)



**Output Waveform** 



#### **Output Load**

1TTL + 30 pF



#### Read Cycle (1/2) (B version)

Parameter	Symbol				Vcc≥	2.7 V				Unit	Condition
		μPD4	48012	μPD4	48012	μPD4	48012	μPD4	48012		
		-B5	-B55X		-B70X		-B85X		10X		
		MIN.	MAX.	MIN.	MAX.	MIN.	MAX.	MIN.	MAX.		
Read cycle time	<b>t</b> RC	55		70		85		100		ns	
Address access time	taa		55		70		85		100	ns	Note 1
/CE1 access time	<b>t</b> co1		55		70		85		100	ns	
CE2 access time	tc02		55		70		85		100	ns	
/OE to output valid	toe		30		35		40		50	ns	
/LB, /UB to output valid	<b>t</b> BA		55		70		85		100	ns	
Output hold from address change	tон	10		10		10		10		ns	
/CE1 to output in low impedance	<b>t</b> LZ1	10		10		10		10		ns	Note 2
CE2 to output in low impedance	t <sub>LZ2</sub>	10		10		10		10		ns	
/OE to output in low impedance	tolz	0		0		0		0		ns	
/LB, /UB to output in low impedance	<b>t</b> BLZ	10		10		10		10		ns	
/CE1 to output in high impedance	t <sub>HZ1</sub>		20		25		30		35	ns	
CE2 to output in high impedance	t <sub>HZ2</sub>		20		25		30		35	ns	
/OE to output in high impedance	tонz		20		25		30		35	ns	
/LB, /UB to output in high impedance	<b>t</b> внz		20		25		30		35	ns	

Notes 1. The output load is 1TTL + 50 pF.

2. The output load is 1TTL + 5 pF.

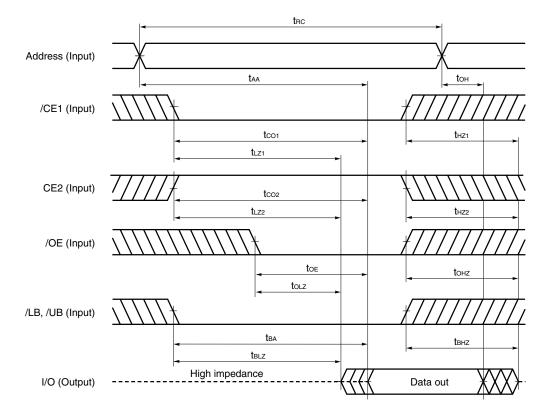
## Read Cycle (2/2) (C version)

Parameter	Symbol				Vcc≥	2.2 V				Unit	Condition
		μPD4	48012	μPD4	48012	μPD4	48012	μPD4	48012		
		-C7	-C70X		-C85X		-C10X		12X		
		MIN.	MAX.	MIN.	MAX.	MIN.	MAX.	MIN.	MAX.		
Read cycle time	<b>t</b> RC	70		85		100		120		ns	
Address access time	taa		70		85		100		120	ns	Note 1
/CE1 access time	<b>t</b> co1		70		85		100		120	ns	
CE2 access time	<b>t</b> co2		70		85		100		120	ns	
/OE to output valid	toe		35		40		50		60	ns	
/LB, /UB to output valid	<b>t</b> BA		70		85		100		120	ns	
Output hold from address change	tон	10		10		10		10		ns	
/CE1 to output in low impedance	<b>t</b> LZ1	10		10		10		10		ns	Note 2
CE2 to output in low impedance	t <sub>LZ2</sub>	10		10		10		10		ns	
/OE to output in low impedance	tolz	0		0		0		0		ns	
/LB, /UB to output in low impedance	<b>t</b> BLZ	10		10		10		10		ns	
/CE1 to output in high impedance	<b>t</b> HZ1		25		30		35		40	ns	
CE2 to output in high impedance	t <sub>HZ2</sub>		25		30		35		40	ns	
/OE to output in high impedance	tонz		25		30		35		40	ns	
/LB, /UB to output in high impedance	<b>t</b> внz		25		30		35		40	ns	

**Notes 1.** The output load is 1TTL + 30 pF.

2. The output load is 1TTL + 5 pF.

## **Read Cycle Timing Chart**



**Remark** In read cycle, /WE should be fixed to high level.



#### Write Cycle (1/2) (B version)

Parameter	Symbol				Vcc≥	2.7 V				Unit	Condition
		μPD4	48012	μPD4	48012	μPD4	μPD448012		48012		
		-B	-B55X		-B70X		35X	-B1	I0X		
		MIN.	MAX.	MIN.	MAX.	MIN.	MAX.	MIN.	MAX.		
Write cycle time	twc	55		70		85		100		ns	
/CE1 to end of write	tcw1	50		55		70		80		ns	
CE2 to end of write	tcw2	50		55		70		80		ns	
/LB, /UB to end of write	<b>t</b> <sub>BW</sub>	50		55		70		80		ns	
Address valid to end of write	taw	50		55		70		80		ns	
Address setup time	<b>t</b> as	0		0		0		0		ns	
Write pulse width	<b>t</b> wp	45		50		55		60		ns	
Write recovery time	twr	0		0		0		0		ns	
Data valid to end of write	<b>t</b> <sub>DW</sub>	25		30		35		40		ns	
Data hold time	<b>t</b> DH	0		0		0		0		ns	
/WE to output in high impedance	twнz		20		25		30		35	ns	Note
Output active from end of write	tow	5		5		5		5		ns	

**Note** The output load is 1TTL + 5 pF.

## Write Cycle (2/2) (C version)

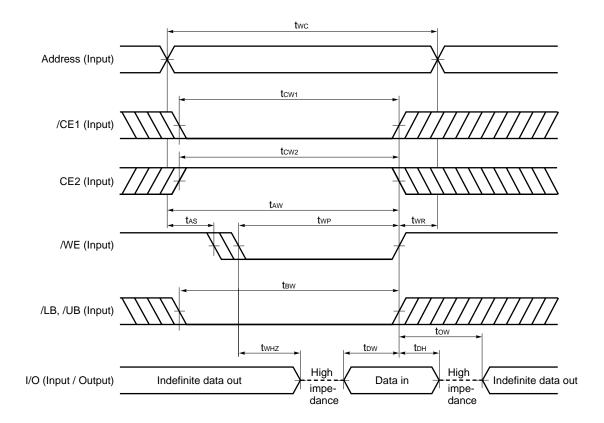
Parameter	Symbol				Vcc ≥	2.2V				Unit	Condition
		μPD4	48012	μPD4	48012	μPD4	48012 μPD4		48012		
		-C7	-C70X		35X	-C1	10X	-C1	12X		
		MIN.	MAX.	MIN.	MAX.	MIN.	MAX.	MIN.	MAX.		
Write cycle time	twc	70		85		100		120		ns	
/CE1 to end of write	tcw1	55		70		80		100		ns	
CE2 to end of write	tcw2	55		70		80		100		ns	
/LB, /UB to end of write	<b>t</b> <sub>BW</sub>	55		70		80		100		ns	
Address valid to end of write	taw	55		70		80		100		ns	
Address setup time	<b>t</b> as	0		0		0		0		ns	
Write pulse width	<b>t</b> wp	50		55		60		85		ns	
Write recovery time	twr	0		0		0		0		ns	
Data valid to end of write	<b>t</b> <sub>DW</sub>	30		35		40		60		ns	
Data hold time	<b>t</b> DH	0		0		0		0		ns	
/WE to output in high impedance	twнz		25		30		35		40	ns	Note
Output active from end of write	tow	5		5		5		5		ns	

Note The output load is 1TTL + 5 pF.

Data Sheet M14466EJ7V0DS 11



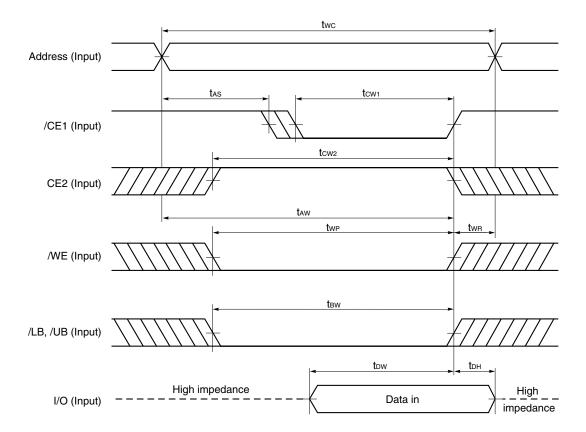
#### Write Cycle Timing Chart 1 (/WE Controlled)



- Cautions 1. During address transition, at least one of pins /CE1, CE2, /WE should be inactivated.
  - 2. Do not input data to the I/O pins while they are in the output state.
- **Remarks 1.** Write operation is done during the overlap time of a low level /CE1, /WE, /LB and/or /UB, and a high level CE2.
  - 2. If /CE1 changes to low level at the same time or after the change of /WE to low level, or if CE2 changes to high level at the same time or after the change of /WE to low level, the I/O pins will remain high impedance state.
  - 3. When /WE is at low level, the I/O pins are always high impedance. When /WE is at high level, read operation is executed. Therefore /OE should be at high level to make the I/O pins high impedance.



## **Write Cycle Timing Chart 2 (/CE1 Controlled)**

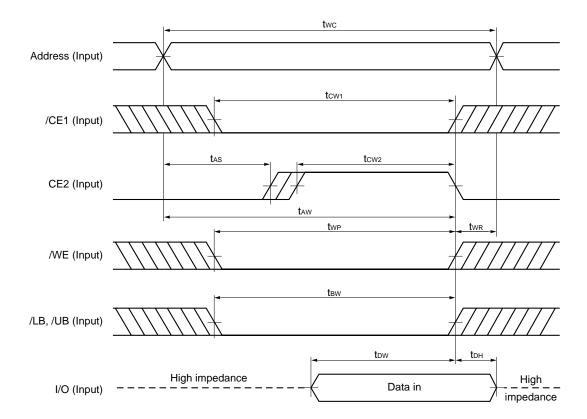


Cautions 1. During address transition, at least one of pins /CE1, CE2, /WE should be inactivated.

2. Do not input data to the I/O pins while they are in the output state.

**Remark** Write operation is done during the overlap time of a low level /CE1, /WE, /LB and/or /UB, and a high level CE2.

## Write Cycle Timing Chart 3 (CE2 Controlled)

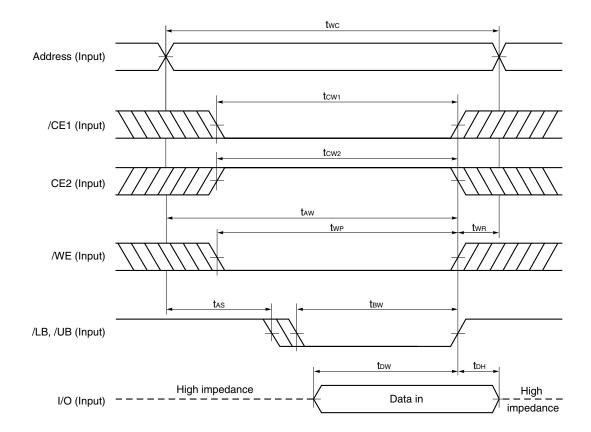


Cautions 1. During address transition, at least one of pins /CE1, CE2, /WE should be inactivated.

2. Do not input data to the I/O pins while they are in the output state.

**Remark** Write operation is done during the overlap time of a low level /CE1, /WE, /LB and/or /UB, and a high level CE2.

#### Write Cycle Timing Chart 4 (/LB, /UB Controlled)



Cautions 1. During address transition, at least one of pins /CE1, CE2, /WE should be inactivated.

2. Do not input data to the I/O pins while they are in the output state.

**Remark** Write operation is done during the overlap time of a low level /CE1, /WE, /LB and/or /UB, and a high level CE2.



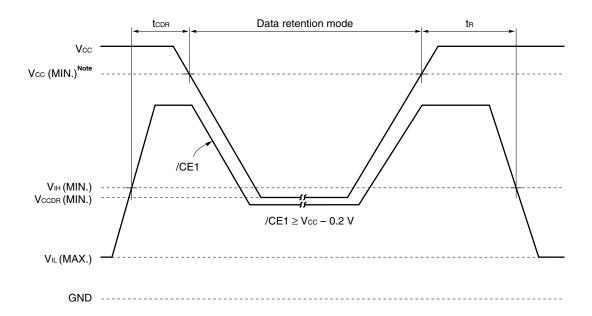
## Low Vcc Data Retention Characteristics ( $T_A = -25 \text{ to } +85^{\circ}\text{C}$ )

Parameter	Symbol	Test Condition	Vcc ≥ 2.7 V			Vcc ≥ 2.2 V			Unit
			μPD448012			μPD448012			
			-B××X			-C××X			
			MIN.	TYP.	MAX.	MIN.	TYP.	MAX.	
Data retention	Vccdr1	/CE1 ≥ Vcc - 0.2 V, CE2 ≥ Vcc - 0.2 V	1.0		3.6	1.0		3.6	V
supply voltage	Vccdr2	CE2 ≤ 0.2 V	1.0		3.6	1.0		3.6	
	Vccdr3	/LB = /UB ≥ Vcc – 0.2 V,	1.0		3.6	1.0		3.6	
		/CE1 ≤ 0.2 V, CE2 ≥ Vcc – 0.2 V							
Data retention	ICCDR1	Vcc = 1.5 V, /CE1 ≥ Vcc – 0.2 V,		0.5	6.0		0.5	6.0	μΑ
supply current		CE2 ≥ Vcc - 0.2 V							
	ICCDR2	Vcc = 1.5 V, CE2 ≤ 0.2 V		0.5	6.0		0.5	6.0	
	Iccdr3	Vcc = 1.5 V, /LB = /UB ≥ Vcc – 0.2 V,		0.5	6.0		0.5	6.0	
		/CE1 ≤ 0.2 V, CE2 ≥ Vcc – 0.2 V							
Chip deselection	tcdr		0			0			ns
to data retention									
mode									
Operation	<b>t</b> R		t <sub>RC</sub> Note			t <sub>RC</sub> Note			ns
recovery time									

 $\textbf{Note} \quad t_{\text{RC}} : \text{Read cycle time}$ 

#### **Data Retention Timing Chart**

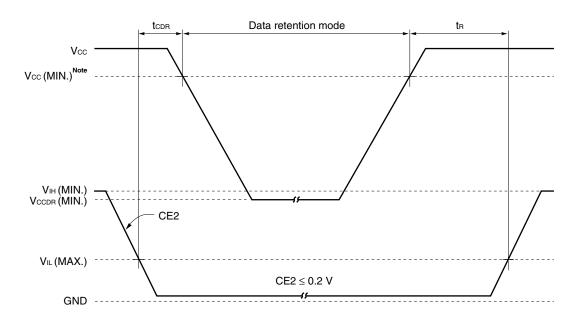
#### (1) /CE1 Controlled



Note B version: 2.7 V, C version: 2.2 V

**Remark** On the data retention mode by controlling /CE1, the input level of CE2 must be  $\geq$  Vcc - 0.2 V or  $\leq$  0.2 V. The other pins (Address, I/O, /WE, /OE, /LB, /UB) can be in high impedance state.

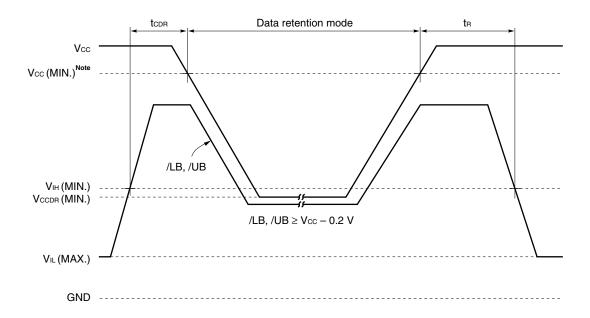
#### (2) CE2 Controlled



Note B version: 2.7 V, C version: 2.2 V

**Remark** On the data retention mode by controlling CE2, the other pins (/CE1, Address, I/O, /WE, /OE, /LB, /UB) can be in high impedance state.

#### (3) /LB, /UB Controlled



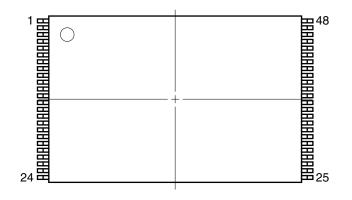
Note B version: 2.7 V, C version: 2.2 V

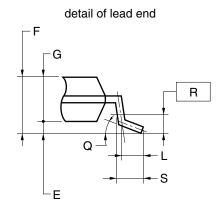
**Remark** On the data retention mode by controlling /LB and /UB, the input level of /CE1 and CE2 must be  $\geq Vcc - 0.2 \text{ V or } \leq 0.2 \text{ V}$ . The other pins (Address, I/O, /WE, /OE) can be in high impedance state.

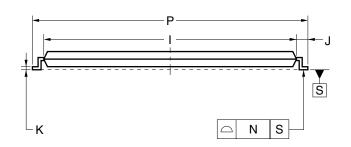


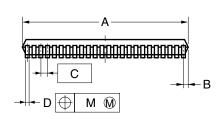
#### **Package Drawing**

## 48-PIN PLASTIC TSOP(I) (12x18)









#### **NOTES**

- 1. Each lead centerline is located within 0.10 mm of its true position (T.P.) at maximum material condition.
- 2. "A" excludes mold flash. (Includes mold flash: 12.4 mm MAX.)

ITEM	MILLIMETERS		
Α	12.0±0.1		
В	0.45 MAX.		
С	0.5 (T.P.)		
D	0.22±0.05		
E	0.1±0.05		
F	1.2 MAX.		
G	1.0±0.05		
I	16.4±0.1		
J	0.8±0.2		
K	0.145±0.05		
L	0.5		
М	0.10		
N	0.10		
Р	18.0±0.2		
Q	3°+5° -3°		
R	0.25		
S	0.60±0.15		

S48GY-50-MJH1-1

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#### **Recommended Soldering Conditions**

Please consult with our sales offices for soldering conditions of the  $\mu$ PD448012-X.

#### **Types of Surface Mount Device**

 $\mu PD448012GY-BxxX-MJH \qquad : 48-pin PLASTIC TSOP (I) (12x18) (Normal bent)$   $\mu PD448012GY-CxxX-MJH \qquad : 48-pin PLASTIC TSOP (I) (12x18) (Normal bent)$   $\mu PD448012GY-BxxX-MJH-A \qquad : 48-pin PLASTIC TSOP (I) (12x18) (Normal bent)$   $\mu PD448012GY-CxxX-MJH-A \qquad : 48-pin PLASTIC TSOP (I) (12x18) (Normal bent)$ 

#### <R> Quality Grade

- A quality grade of the products is "Standard".
- Anti-radioactive design is not implemented in the products.
- Semiconductor devices have the possibility of unexpected defects by affection of cosmic ray that reach to the ground and so forth.



## **Revision History**

Edition/	Page		Type of	Location	Description
Date	This	Previous	revision		(Previous edition $ o$ This edition)
	edition	edition			
7th edition/	p.20	p.20	Addition	Quality Grade	Section of Quality Grade has been added.
Sep. 2006					

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 $\mu$ PD448012-X



[MEMO]



#### NOTES FOR CMOS DEVICES -

#### VOLTAGE APPLICATION WAVEFORM AT INPUT PIN

Waveform distortion due to input noise or a reflected wave may cause malfunction. If the input of the CMOS device stays in the area between  $V_{\rm IL}$  (MAX) and  $V_{\rm IH}$  (MIN) due to noise, etc., the device may malfunction. Take care to prevent chattering noise from entering the device when the input level is fixed, and also in the transition period when the input level passes through the area between  $V_{\rm IL}$  (MAX) and  $V_{\rm IH}$  (MIN).

#### (2) HANDLING OF UNUSED INPUT PINS

Unconnected CMOS device inputs can be cause of malfunction. If an input pin is unconnected, it is possible that an internal input level may be generated due to noise, etc., causing malfunction. CMOS devices behave differently than Bipolar or NMOS devices. Input levels of CMOS devices must be fixed high or low by using pull-up or pull-down circuitry. Each unused pin should be connected to VDD or GND via a resistor if there is a possibility that it will be an output pin. All handling related to unused pins must be judged separately for each device and according to related specifications governing the device.

#### ③ PRECAUTION AGAINST ESD

A strong electric field, when exposed to a MOS device, can cause destruction of the gate oxide and ultimately degrade the device operation. Steps must be taken to stop generation of static electricity as much as possible, and quickly dissipate it when it has occurred. Environmental control must be adequate. When it is dry, a humidifier should be used. It is recommended to avoid using insulators that easily build up static electricity. Semiconductor devices must be stored and transported in an anti-static container, static shielding bag or conductive material. All test and measurement tools including work benches and floors should be grounded. The operator should be grounded using a wrist strap. Semiconductor devices must not be touched with bare hands. Similar precautions need to be taken for PW boards with mounted semiconductor devices.

#### **4** STATUS BEFORE INITIALIZATION

Power-on does not necessarily define the initial status of a MOS device. Immediately after the power source is turned ON, devices with reset functions have not yet been initialized. Hence, power-on does not guarantee output pin levels, I/O settings or contents of registers. A device is not initialized until the reset signal is received. A reset operation must be executed immediately after power-on for devices with reset functions.

#### (5) POWER ON/OFF SEQUENCE

In the case of a device that uses different power supplies for the internal operation and external interface, as a rule, switch on the external power supply after switching on the internal power supply. When switching the power supply off, as a rule, switch off the external power supply and then the internal power supply. Use of the reverse power on/off sequences may result in the application of an overvoltage to the internal elements of the device, causing malfunction and degradation of internal elements due to the passage of an abnormal current.

The correct power on/off sequence must be judged separately for each device and according to related specifications governing the device.

#### (6) INPUT OF SIGNAL DURING POWER OFF STATE

Do not input signals or an I/O pull-up power supply while the device is not powered. The current injection that results from input of such a signal or I/O pull-up power supply may cause malfunction and the abnormal current that passes in the device at this time may cause degradation of internal elements. Input of signals during the power off state must be judged separately for each device and according to related specifications governing the device.

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